8-bit serial-in/serial-out or parallel-out shift register with output latches

Rev. 1 — 12 July 2012

Product data sheet

1. General description

The 74AHC595-Q100; 74AHCT595-Q100 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7A.

The 74AHC595-Q100; 74AHCT595-Q100 are 8-stage serial shift registers with a storage register and 3-state outputs. The registers have separate clocks.

Data is shifted on the positive-going transitions of the shift register clock input (SHCP). The data in each register is transferred to the storage register on a positive-going transition of the storage register clock input (STCP). If both clocks are connected together, the shift register is always one clock pulse ahead of the storage register.

The shift register has a serial input (DS) and a serial standard output (Q7S) for cascading. It is also provided with asynchronous reset (active LOW) for all 8 shift register stages. The storage register has 8 parallel 3-state bus driver outputs. Data in the storage register appears at the output whenever the output enable input (\overline{OE}) is LOW.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt trigger action
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - The 74AHC595-Q100 operates with CMOS input levels
 - The 74AHCT595-Q100 operates with TTL input levels
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Multiple package options



8-bit serial-in/serial-out or parallel-out shift register with output latches

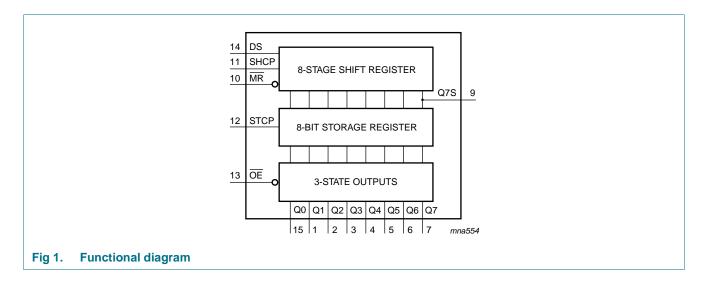
3. Applications

- Serial-to-parallel data conversion
- Remote control holding register

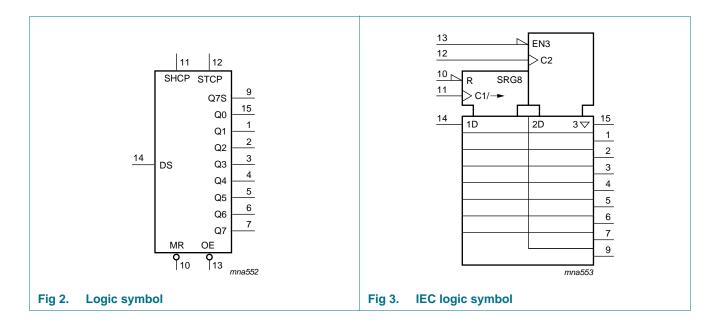
4. Ordering information

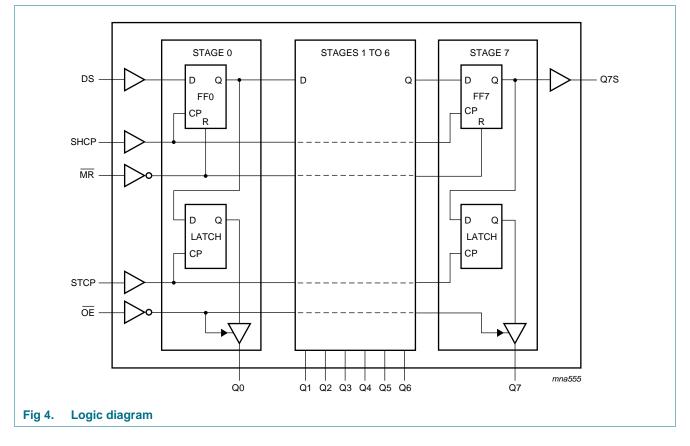
Table 1. Ordering in	nformation			
Type number	Package			
	Temperature range	Name	Description	Version
74AHC595-Q100				
74AHC595D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHC595PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHC595BQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1
74AHCT595-Q100				
74AHCT595D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHCT595PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHCT595BQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1

5. Functional diagram



8-bit serial-in/serial-out or parallel-out shift register with output latches





74AHC_AHCT595_Q100

8-bit serial-in/serial-out or parallel-out shift register with output latches

6. Pinning information

6.1 Pinning

74AHC595-Q100 74AHCT595-Q100 202 terminal 1 δ index area 74AHC595-Q100 -16 74AHCT595-Q100 Q2 2) (15 Q0 3) Q3 (14 DS 16 V_{CC} Q1 1 ŌE Q2 2 15 Q0 4) (13 Q4 Q3 3 14 DS STCP Q5 5) (12 Q4 4 13 OE 6) (11 SHCP Q6 GND⁽¹⁾ Q5 5 12 STCP Q7 7) (10 MR Q6 6 11 SHCP 6 യി Q7 7 10 MR GND Q7S aaa-003870 9 Q7S GND 8 Transparent top view aaa-003869 (1) This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to GND. Pin configuration SO16 and TSSOP16 **Pin configuration DHVQFN16** Fig 5. Fig 6.

6.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
Q1	1	parallel data output 1
Q2	2	parallel data output 2
Q3	3	parallel data output 3
Q4	4	parallel data output 4
Q5	5	parallel data output 5
Q6	6	parallel data output 6
Q7	7	parallel data output 7
GND	8	ground (0 V)
Q7S	9	serial data output
MR	10	master reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
OE	13	output enable input (active LOW)
DS	14	serial data input
Q0	15	parallel data output 0
V _{CC}	16	supply voltage

74AHC_AHCT595_Q100

All information provided in this document is subject to legal disclaimers.

8-bit serial-in/serial-out or parallel-out shift register with output latches

7. Functional description

Contro	bl			Input	Outpu	ıt	Function
SHCP	STCP	OE	MR	DS	Q7S	Qn	
Х	Х	L	L	х	L	NC	a LOW-level on $\overline{\rm MR}$ only affects the shift registers
Х	\uparrow	L	L	Х	L	L	empty shift register loaded into storage register
Х	Х	Н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state
1	Х	L	Н	Η	Q6S	NC	logic HIGH-level shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S).
Х	↑	L	Н	Х	NC	QnS	contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages
↑	↑	L	Η	х	Q6S	QnS	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the paralle output stages

[1] H = HIGH voltage state;

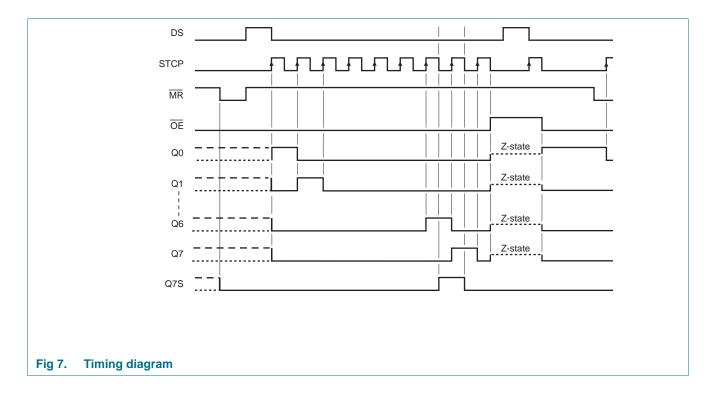
L = LOW voltage state;

 \uparrow = LOW-to-HIGH transition;

X = don't care;

NC = no change;

Z = high-impedance OFF-state.



8-bit serial-in/serial-out or parallel-out shift register with output latches

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	<u>[1]</u> –20	-	mA
I _{OK}	output clamping current	V_O < –0.5 V or V_O > V_{CC} + 0.5 V	<u>[1]</u> –20	+20	mA
lo	output current	$V_{\rm O}$ = –0.5 V to (V_{\rm CC} + 0.5 V)	-25	+25	mA
I _{CC}	supply current		-	+75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SO16 packages: above 70 °C the value of P_{tot} derates linearly at 8 mW/K.
 For TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly at 5.5 mW/K.
 For DHVQFN16 packages: above 60 °C the value of P_{tot} derates linearly at 4.5 mW/K.

9. Recommended operating conditions

Table 5.	Operating conditions					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC59	5-Q100					
V _{CC}	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 3.0 V to 3.6 V	-	-	100	ns/V
		V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V
74AHCT5	i95-Q100					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V

8-bit serial-in/serial-out or parallel-out shift register with output latches

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	;	–40 °C	to +85 °C	−40 °C	to +125 °C	Uni
			Min	Тур	Max	Min	Max	Min	Max	
74AHC5	95-Q100									
V _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
VIL	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{он}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = -50 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -50 \ \mu A; \ V_{CC} = 3.0 \ V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O} = -50 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 50 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I_{O} = 8.0 mA; V_{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{OZ}	OFF-state output current		-	-	±0.25	-	±2.5	-	±10	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	4.0	-	40	-	80	μA
CI	input capacitance		-	3	10	-	10	-	10	pF
74AHCT	595-Q100									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
-	output voltage	$I_{\rm O} = -50 \ \mu {\rm A}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{\rm O} = -8.0 \rm{mA}$	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
~-	output voltage	$I_{O} = 50 \ \mu A$	-	0	0.1	-	0.1	-	0.1	V
		~ '								

74AHC_AHCT595_Q100

7 of 22

8-bit serial-in/serial-out or parallel-out shift register with output latches

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

	=	* *				=				
Symbol	Parameter	Conditions		25 °C	;	–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{OZ}	OFF-state output current		-	-	±0.25	-	±2.5	-	±10	μΑ
I _{CC}	supply current		-	-	4.0	-	40	-	80	μA
ΔI_{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; $I_O = 0 A$; V _{CC} = 4.5 V to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
CI	input capacitance		-	3	10	-	10	-	10	pF

8-bit serial-in/serial-out or parallel-out shift register with output latches

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 13</u>.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	−40 °C t	to +125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
74AHC5	95-Q100										
pd	propagation	SHCP to Q7S; see Figure 8	[2]								
	delay	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$									
		C _L = 15 pF		-	5.7	13.0	1.0	15.0	1.0	16.5	ns
		C _L = 50 pF		-	7.7	16.5	1.0	18.5	1.0	20.1	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.0	8.2	1.0	9.4	1.0	10.5	ns
		C _L = 50 pF		-	5.4	10.0	1.0	11.4	1.0	12.5	ns
		STCP to Qn; see Figure 9	[2]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.9	11.9	1.0	13.5	1.0	15.0	ns
		C _L = 50 pF		-	7.7	15.4	1.0	17.0	1.0	18.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.2	7.4	1.0	8.5	1.0	9.5	ns
		C _L = 50 pF		-	5.5	9.0	1.0	10.5	1.0	11.5	ns
		MR to Q7S; see Figure 11	[3]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.9	12.8	1.0	13.7	1.0	15.0	ns
		C _L = 50 pF		-	7.4	16.3	1.0	17.2	1.0	18.7	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.4	8.0	1.0	9.1	1.0	10.0	ns
		C _L = 50 pF		-	5.6	10.0	1.0	11.1	1.0	12.0	ns
en	enable time	OE to Qn; see Figure 12	[4]								
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$									
		C _L = 15 pF		-	5.6	11.5	1.0	13.5	1.0	15.0	ns
		C _L = 50 pF		-	7.4	15.0	1.0	17.0	1.0	18.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C _L = 15 pF		-	4.0	8.6	1.0	10.0	1.0	11.0	ns
		$C_1 = 50 \text{pF}$		-	5.3	10.6	1.0	12.0	1.0	13.0	ns
dis	disable time	OE to Qn; see Figure 12	[5]								
		V _{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.4	11.0	1.0	13.0	1.0	14.5	ns
		$C_L = 50 \text{ pF}$		-	8.7	15.7	1.0	16.2	1.0	17.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 \text{ pF}$		-	3.8	8.0	1.0	9.5	1.0	10.5	ns
		$C_L = 50 \text{ pF}$		-	5.8	10.3	1.0	11.0	1.0	12.0	ns

74AHC_AHCT595_Q100

All information provided in this document is subject to legal disclaimers.

8-bit serial-in/serial-out or parallel-out shift register with output latches

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
max	maximum frequency	SHCP or STCP; see <u>Figure 8</u> and <u>9</u>									
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		80	125	-	60	-	40	-	MH:
		V_{CC} = 4.5 V to 5.5 V		130	170	-	110	-	90	-	MH
W	pulse width	SHCP HIGH or LOW; see <u>Figure 8</u>									
		V_{CC} = 3.0 V to 3.6 V		5.0	-	-	5.0	-	5.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
		STCP HIGH or LOW; see <u>Figure 9</u>									
		V_{CC} = 3.0 V to 3.6 V		5.0	-	-	5.0	-	5.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Figure 11									
		V_{CC} = 3.0 V to 3.6 V		5.0	-	-	5.0	-	5.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
su	set-up time	DS to SHCP; see Figure 9									
		V_{CC} = 3.0 V to 3.6 V		3.5	-	-	3.5	-	3.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		3.0	-	-	3.0	-	3.0	-	ns
		SHCP to STCP; see <u>Figure 10</u>									
		V_{CC} = 3.0 V to 3.6 V		8.5	-	-	8.5	-	8.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		5.0	-	-	5.0	-	5.0	-	ns
h	hold time	DS to SHCP; see Figure 10									
		V_{CC} = 3.0 V to 3.6 V		1.5	-	-	1.5	-	1.5	-	ns
		V_{CC} = 4.5 V to 5.5 V		2.0	-	-	2.0	-	2.0	-	ns
rec	recovery	MR to SHCP; see Figure 11									
	time	V_{CC} = 3.0 V to 3.6 V		3.0	-	-	3.0	-	3.0	-	ns
		V_{CC} = 4.5 V to 5.5 V		2.5	-	-	2.5	-	2.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{\text{CC}}$	<u>[6]</u> [7]	-	180	-	-	-	-	-	pF
4AHCT	-	_{cc} = 4.5 V to 5.5 V									
pd	propagation	SHCP to Q7S; see Figure 8	[2]								
-	delay	C _L = 15 pF		-	3.8	8.2	1.0	9.0	1.0	10.0	ns
		$C_L = 50 \text{ pF}$		-	5.2	10.0	1.0	11.0	1.0	12.0	ns
		STCP to Qn; see Figure 9	[2]								
		C _L = 15 pF		-	4.0	7.4	1.0	8.5	1.0	9.5	ns
		$C_L = 50 \text{ pF}$		-	5.3	9.0	1.0	10.5	1.0	11.5	ns
		MR to Q7S; see Figure 11	[3]								
		$C_{L} = 15 \text{pF}$		-	4.6	8.2	1.0	9.5	1.0	10.5	ns
		$C_L = 50 \text{ pF}$		_	5.8	10.5	1.0	11.5	1.0	12.5	ns

8-bit serial-in/serial-out or parallel-out shift register with output latches

Table 7. Dynamic characteristics ... continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
t _{en}	enable time	OE to Qn; see Figure 12	[4]								
		C _L = 15 pF		-	4.8	9.0	1.0	11.0	1.0	12.0	ns
		C _L = 50 pF		-	6.2	11.6	1.0	13.0	1.0	14.5	ns
t _{dis}	disable time	OE to Qn; see Figure 12	[5]								
		C _L = 15 pF		-	3.6	6.9	1.0	8.0	1.0	9.0	ns
		C _L = 50 pF		-	5.8	10.3	1.0	11.0	1.0	12.0	ns
f _{max}	maximum frequency	SHCP and STCP; see <u>Figure 8</u> and <u>Figure 9</u>		130	170	-	110	-	90	-	MHz
t _W	pulse width	SHCP HIGH or LOW; see <u>Figure 8</u>		5.0	-	-	5.0	-	5.0	-	ns
		STCP HIGH or LOW; see Figure 9		5.0	-	-	5.0	-	5.0	-	ns
		MR LOW; see Figure 11		5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	DS to SHCP; see Figure 9		3.0	-	-	3.0	-	3.0	-	ns
		SHCP to STCP; see <u>Figure 10</u>		5.0	-	-	5.0	-	5.0	-	ns
t _h	hold time	DS to SHCP; see Figure 10		2.0	-	-	2.0	-	2.0	-	ns
t _{rec}	recovery time	MR to SHCP; see Figure 11		3.0	-	-	3.0	-	3.0	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{\text{CC}}$	<u>[6]</u> [7]	-	190	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage.

 $\label{eq:tpd} [2] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$

[3] t_{pd} is the same as t_{PHL} only.

- [4] t_{en} is the same as t_{PZL} and t_{PZH} .
- [5] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[6] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma(C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs;

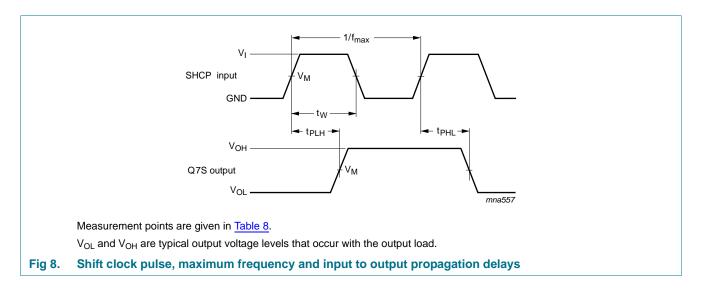
 C_L = output load capacitance in pF;

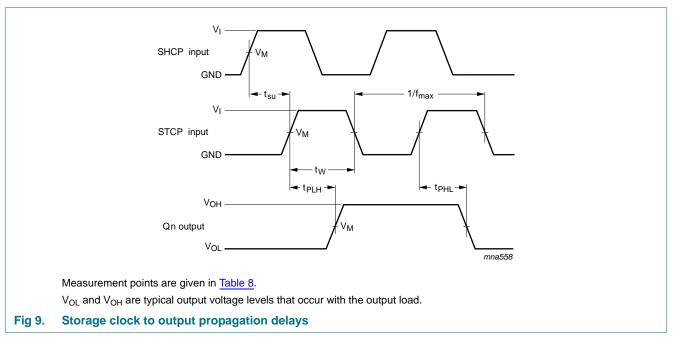
 V_{CC} = supply voltage in V.

[7] All 9 outputs switching.

8-bit serial-in/serial-out or parallel-out shift register with output latches

12. Waveforms





8-bit serial-in/serial-out or parallel-out shift register with output latches

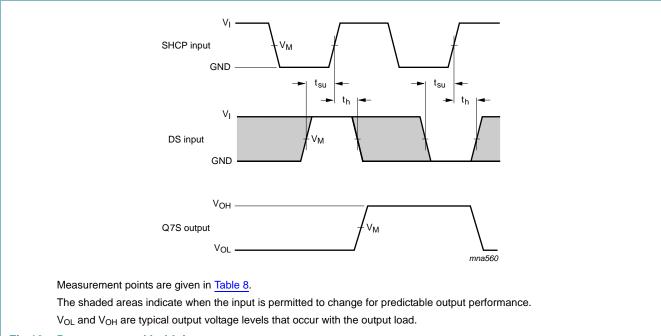
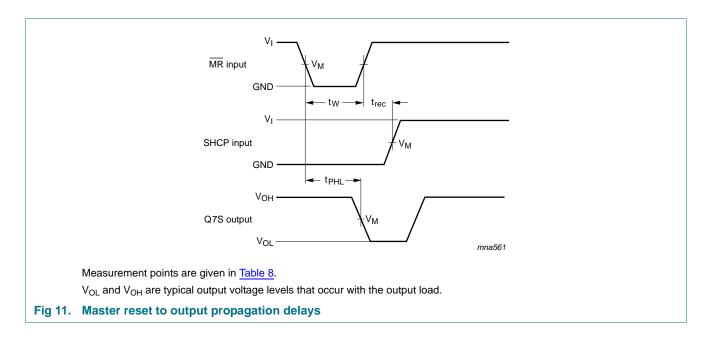


Fig 10. Data set-up and hold times



8-bit serial-in/serial-out or parallel-out shift register with output latches

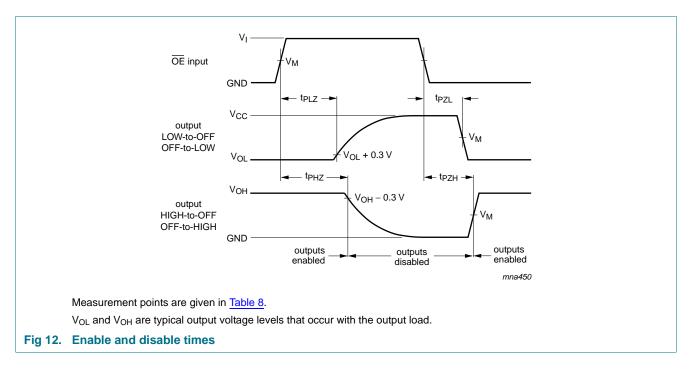


Table 8.Measurement points

Туре	Input	Output
	V _M	V _M
74AHC595-Q100	0.5V _{CC}	0.5V _{CC}
74AHCT595-Q100	1.5 V	0.5V _{CC}

8-bit serial-in/serial-out or parallel-out shift register with output latches

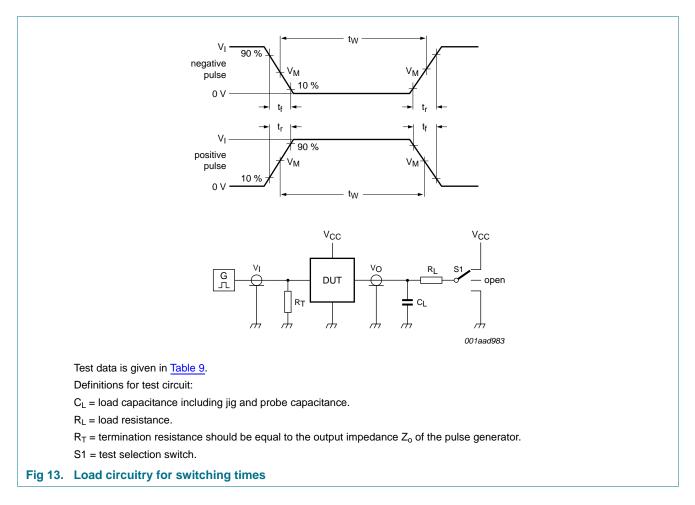


Table 9. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74AHC595-Q100	V _{CC}	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74AHCT595-Q100	3.0 V	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

8-bit serial-in/serial-out or parallel-out shift register with output latches

13. Package outline

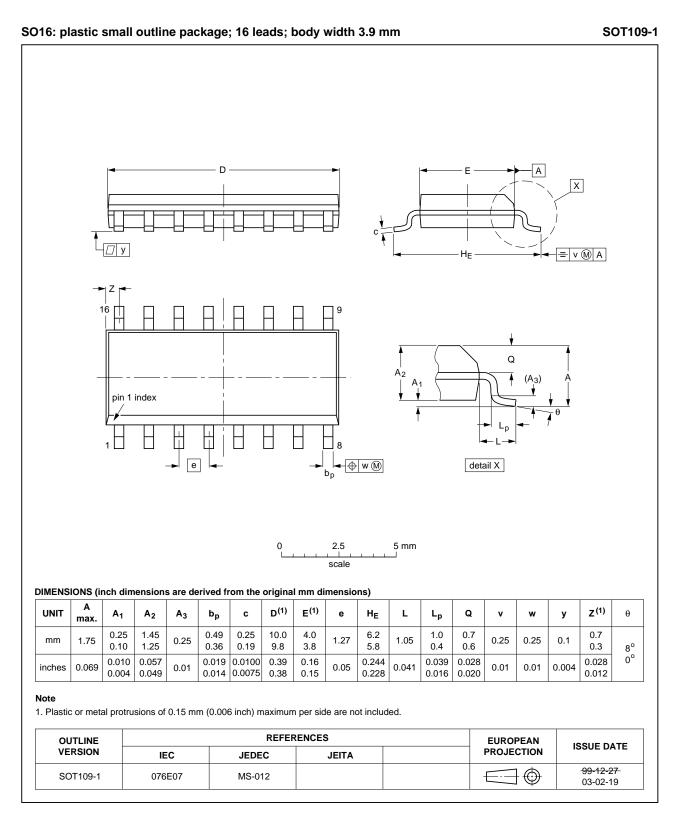


Fig 14. Package outline SOT109-1 (SO16)

All information provided in this document is subject to legal disclaimers.

8-bit serial-in/serial-out or parallel-out shift register with output latches

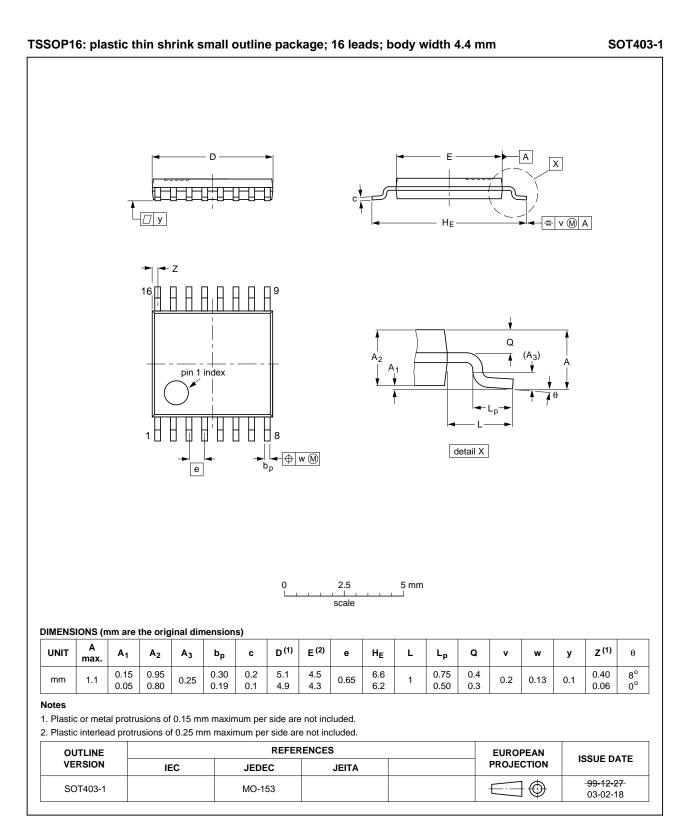
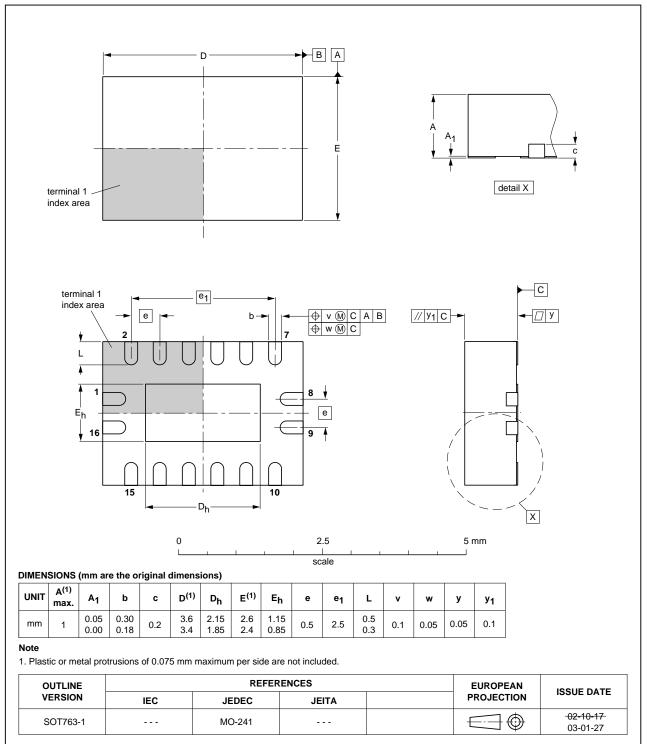


Fig 15. Package outline SOT403-1 (TSSOP16)

All information provided in this document is subject to legal disclaimers.

8-bit serial-in/serial-out or parallel-out shift register with output latches



DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 16. Package outline SOT763-1 (DHVQFN16)

8-bit serial-in/serial-out or parallel-out shift register with output latches

14. Abbreviations

	Abbreviations		
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal-Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		
TTL	Transistor-Transistor Logic		
MIL	Military		

15. Revision history

Table 11. Revision history	Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AHC_AHCT595_Q100 v.1	20120712	Product data sheet	-	-			

8-bit serial-in/serial-out or parallel-out shift register with output latches

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications - This NXP

Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

NXP Semiconductors

74AHC595-Q100; 74AHCT595-Q100

8-bit serial-in/serial-out or parallel-out shift register with output latches

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

NXP Semiconductors

74AHC595-Q100; 74AHCT595-Q100

8-bit serial-in/serial-out or parallel-out shift register with output latches

18. Contents

1	General description 1
2	Features and benefits 1
3	Applications 2
4	Ordering information 2
5	Functional diagram 2
6	Pinning information 4
6.1	Pinning
6.2	Pin description 4
7	Functional description 5
8	Limiting values 6
9	Recommended operating conditions 6
10	Static characteristics 7
11	Dynamic characteristics 9
12	Waveforms 12
13	Package outline 16
14	Abbreviations 19
15	Revision history 19
16	Legal information
16.1	Data sheet status 20
16.2	Definitions
16.3	Disclaimers 20
16.4	Trademarks 21
17	Contact information 21
18	Contents 22

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2012.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 12 July 2012 Document identifier: 74AHC_AHCT595_Q100